

#### MICROPOWER RAIL-TO-RAIL CMOS OPERATIONAL AMPLIFIER

#### **GENERAL DESCRIPTION**

The ALD1701A/ALD1701B/ALD1701/ALD1701G is a monolithic CMOS micropower high slew rate operational amplifier intended for a broad range of analog applications using  $\pm 1 \text{V}$  to  $\pm 5 \text{V}$  dual power supply systems, as well as +2 V to +10 V battery operated systems. All device characteristics are specified for +5 V single supply or  $\pm 2.5 \text{V}$  dual supply systems. Supply current is  $250 \mu \text{A}$  maximum at 5 V supply voltage. It is manufactured with Advanced Linear Devices' enhanced ACMOS silicon gate CMOS process.

The ALD1701A/ALD1701B/ALD1701/ALD1701G is designed to offer a trade-off of performance parameters providing a wide range of desired specifications. It has been developed specifically for the +5V single supply or  $\pm 1V$  to  $\pm 5V$  dual supply user and offers the popular industry standard pin configuration of  $\mu A741$  and ICL7611 types.

Several important characteristics of the device make application easier to implement at those voltages. First, the operational amplifier can operate with rail to rail input and output voltages. This means the signal input voltage and output voltage can be equal to the positive and negative supply voltages. This feature allows numerous analog serial stages and flexibility in input signal bias levels. Second, the device was designed to accommodate mixed applications where digital and analog circuits may operate off the same power supply or battery. Third, the output stage can typically drive up to 50pF capacitive and  $10 \mathrm{K}\Omega$  resistive loads.

These features, combined with extremely low input currents, high open loop voltage gain of 100V/mV, useful bandwidth of 700KHz, a slew rate of 0.7V/ $\mu$ s, low power dissipation of 0.5mW, low offset voltage and temperature drift, make the ALD1701 a versatile, micropower operational amplifier.

The ALD1701A/ALD1701B/ALD1701/ALD1701G, designed and fabricated with silicon gate CMOS technology, offers 1pA typical input bias current. On chip offset voltage trimming allows the device to be used without nulling in most applications. Additionally, robust design and rigorous screening make this device especially suitable for operation in temperature-extreme environments and rugged conditions.

#### **ORDERING INFORMATION** ("L" suffix denotes lead-free (RoHS))

		•	` ''								
	Operating Temperature Range										
L	0°C to +70°C	0°C to +70°C	-55°C to 125°C								
	8-Pin Small Outline	8-Pin Plastic Dip	8-Pin CERDIP								
L	Package (SOIC)	Package	Package								
	ALD1701ASAL	ALD1701APAL	ALD1701ADA								
	ALD1701BSAL	ALD1701BPAL	ALD1701BDA								
	ALD1701SAL	ALD1701PAL	ALD1701DA								
	ALD1701GSAL	ALD1701GPAL	ALD1701GDA								

<sup>\*</sup> Contact factory for leaded (non-RoHS) or high temperature versions.

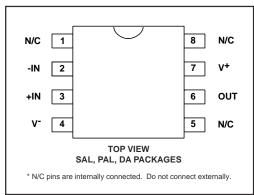
#### **FEATURES**

- All parameters specified for +5V single supply or ±2.5V dual supply systems
- Rail to rail input and output voltage ranges
- No frequency compensation required -unity gain stable
- Extremely low input bias currents --1.0pA typical (30pA max.)
- Ideal for high source impedance applications
- Dual power supply ±1.0V to ±5.0V operation
- Single power supply +2.0V to +10.0V operation
- High voltage gain -- typically 100V/mV @ ±2.5V(100dB)
- Drive as low as 10KΩ load
- · Output short circuit protected
- Unity gain bandwidth of 0.7MHz
- Slew rate of 0.7V/μs
- Low power dissipation
- Suitable for rugged, temperature-extreme environments

#### **APPLICATIONS**

- Voltage amplifier
- · Voltage follower/buffer
- · Charge integrator
- · Photodiode amplifier
- Data acquisition systems
- High performance portable instruments
- Signal conditioning circuits
- Sensor and transducer amplifiers
- Low leakage amplifiers
- Active filters
- Sample/Hold amplifier
- Picoammeter
- · Current to voltage converter

#### **PIN CONFIGURATION**



### **ABSOLUTE MAXIMUM RATINGS**

Supply voltage, V+	10.6V
Differential input voltage range	-0.3V to V++0.3V
Power dissipation	600 mW
Operating temperature range SAL, PAL packages	0°C to +70°C
DA package	55°C to +125°C
Storage temperature range	65°C to +150°C
Lead temperature, 10 seconds	+260°C

**CAUTION:** ESD Sensitive Device. Use static control procedures in ESD controlled environment.

# OPERATING ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}C\ V_S = \pm 2.5V$ unless otherwise specified

			1701	١.		1701B			1701			1701G			Test
Parameter	Symbol	Min	Тур	Max	Unit	Conditions									
Supply Voltage	Vs V+	±1.0 2.0		±5.0 10.0	V	Dual Supply Single Supply									
Input Offset Voltage	Vos			0.9 1.7			2.0 2.8			4.5 5.3			10.0 11.0	mV mV	$R_S \le 100 K\Omega$ $0^{\circ}C \le T_A \le +70^{\circ}C$
Input Offset Current	los		1.0	25 240		1.0	25 240		1.0	25 240		1.0	30 450	pA pA	$T_A = 25^{\circ}C$ $0^{\circ}C \le T_A \le +70^{\circ}C$
Input Bias Current	IB		1.0	30 300		1.0	30 300		1.0	30 300		1.0	50 600	pA pA	$T_A = 25^{\circ}C$ $0^{\circ}C \le T_A \le +70^{\circ}C$
Input Voltage Range	V <sub>IR</sub>	-0.3 -2.8		5.3 2.8	V V	$V^{+} = +5V$ $V_{S} = \pm 2.5V$									
Input Resistance	R <sub>IN</sub>		10 <sup>12</sup>		Ω										
Input Offset Voltage Drift	TCV <sub>OS</sub>		7			7			7			7		μV/°C	R <sub>S</sub> ≤ 100KΩ
Power Supply Rejection Ratio	PSRR	70 70	80 80		65 65	80 80		65 65	80 80		60 60	80 80		dB dB	$R_S \le 100 K\Omega$ $0^{\circ}C \le T_A \le +70^{\circ}C$
Common Mode Rejection Ratio	CMRR	70 70	83 83		65 65	83 83		65 65	83 83		60 60	83 83		dB dB	$R_S \le 100 K\Omega$ $0^{\circ}C \le T_A \le +70^{\circ}C$
Large Signal Voltage Gain	A <sub>V</sub>	40 20	100 1000		32 20	100 1000		32 20	100 1000		20 10	80 1000		V/ mV V/ mV V/ mV	$R_{L} = 100 K\Omega$ $R_{L} \ge 1 M\Omega$ $R_{L} = 100 K\Omega$ $0^{\circ}C \le T_{A} \le +70^{\circ}C$
Output Voltage	V <sub>O</sub> low V <sub>O</sub> high	4.99	0.001 4.999	0.01	V V	$R_L = 1M\Omega V^+ = +5V$ $0^{\circ}C \le T_A \le +70^{\circ}C$									
Range	V <sub>O</sub> low V <sub>O</sub> high	2.40	-2.48 2.48	-2.40	V V	$R_L = 100 K\Omega$ $0^{\circ}C \le T_A \le +70^{\circ}C$									
Output Short Circuit Current	I <sub>SC</sub>		1			1			1			1		mA	
Supply Current	IS		120	250		120	250		120	250		120	300	μΑ	V <sub>IN</sub> = 0V No Load
Power Dissipation	PD			1.25			1.25			1.25			1.50	mW	V <sub>S</sub> = ±2.5V

### **OPERATING ELECTRICAL CHARACTERISTICS (cont'd)**

 $T_A = 25^{\circ}C$   $V_S = \pm 2.5V$  unless otherwise specified

			1701A			1701B			1701		·	1701G			Test
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit	Conditions
Input Capacitance	C <sub>IN</sub>		1			1			1			1		pF	
Bandwidth	BW	400	700		400	700		400	700			700		KHz	
Slew Rate	s <sub>R</sub>	0.33	0.7		0.33	0.7		0.33	0.7			0.7		V/μs	A <sub>V</sub> = +1 R <sub>L</sub> = 100KΩ
Rise time	t <sub>r</sub>		0.2			0.2			0.2			0.2		μS	R <sub>L</sub> = 100KΩ
Overshoot Factor			20			20			20			20		%	R <sub>L</sub> =100KΩ C <sub>L</sub> = 50pF
Settling Time	ts		10.0			10.0			10.0			10.0		μS	0.1% A <sub>V</sub> = -R <sub>L</sub> =100KΩ C <sub>L</sub> = 50pF

 $T_A = 25^{\circ}C$   $V_S = \pm 5.0V$  unless otherwise specified

		1701A			1701B		1701		1	701G			Test		
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit	Conditions
Power Supply Rejection Ratio	PSRR		83			83			83			83		dB	RS ≤ 100KΩ
Common Mode Rejection Ratio	CMRR		83			83			83			83		dB	R <sub>S</sub> ≤ 100KΩ
Large Signal Voltage Gain	Ay		250			250			250			250		V/mV	R <sub>L</sub> =100KΩ
Output Voltage Range	VO low	4.90	-4.98 4.98	-4.90	4.90	-4.98 4.98	-4.90	4.90	-4.98 4.98	-4.90	4.90	-4.98 4.98	-4.90	V V	R <sub>L</sub> =100KΩ
Bandwidth	BW		1.0			1.0			1.0			1.0		MHz	
Slew Rate	S <sub>R</sub>		1.0			1.0			1.0			1.0		V/µs	A <sub>V</sub> = +1 C <sub>L</sub> = 50pF

 $V_S = \pm 2.5 \text{V} - 55^{\circ}\text{C} \le T_A \le +125^{\circ}\text{C}$  unless otherwise specified

V3 = ±2.5V 00			1701BDA			1701DA			Test
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Conditions
Input Offset Voltage	Vos			3.0			6.5	mV	R <sub>S</sub> ≤ 100KΩ
Input Offset Current	los			8.0			8.0	nA	
Input Bias Current	Ι <sub>Β</sub>			10.0			10.0	nA	
Power Supply Rejection Ratio	PSRR	60	75		60	75		dB	R <sub>S</sub> ≤ 100KΩ
Common Mode Rejection Ratio	CMRR	60	83		60	83		dB	R <sub>S</sub> ≤ 100KΩ
Large Signal Voltage Gain	Av	15	50		15	50		V/ mV	R <sub>L</sub> = 100KΩ
Output Voltage Range	V <sub>O</sub> low V <sub>O</sub> high	2.35	-2.47 2.45	-2.40	2.35	-2.47 2.45	-2.40	V V	R <sub>L</sub> = 100KΩ

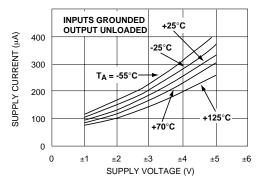
#### **Design & Operating Notes:**

- 1. The ALD1701A/ALD1701B/ALD1701/ALD1701G CMOS operational amplifier uses a 3 gain stage architecture and an improved frequency compensation scheme to achieve large voltage gain, high output driving capability, and better frequency stability. In a conventional CMOS operational amplifier design, compensation is achieved with a pole splitting capacitor together with a nulling resistor. This method is, however, very bias dependent and thus cannot accommodate the large range of supply voltage operation as is required from a stand alone CMOS operational amplifier. The ALD1701A/ALD1701B/ALD1701/ALD1701G is internally compensated for unity gain stability using a novel scheme that does not use a nulling resistor. This scheme produces a clean single pole roll off in the gain characteristics while providing for more than 70 degrees of phase margin at the unity gain frequency.
- 2. The ALD1701A/ALD1701B/ALD1701/ALD1701G has complementary p-channel and n-channel input differential stages connected in parallel to accomplish rail to rail input common mode voltage range. This means that with the ranges of common mode input voltage close to the power supplies, one of the two differential stages is switched off internally. To maintain compatibility with other operational amplifiers, this switching point has been selected to be about 1.5V below the positive supply voltage. Since offset voltage trimming on the ALD1701A/ALD1701B/ALD1701/ALD1701G is made when the input voltage is symmetrical to the supply voltages, this internal switching does not affect a large variety of applications such as an inverting amplifier or non-inverting amplifier with a gain larger than 2.5 (5V operation), where the common mode voltage does not make excursions above this switching point. The user should however, be aware that this switching does take place if the operational amplifier is connected as a unity gain buffer, and should make provision in his design to allow for input offset voltage variations.
- The input bias and offset currents are essentially input protection diode reverse bias leakage currents, and are typically less than 1pA

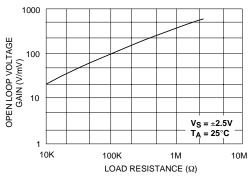
- at room temperature. This low input bias current assures that the analog signal from the source will not be distorted by input bias currents. Normally, this extremely high input impedance of greater than  $10^{12}\Omega$  would not be a problem as the source impedance would limit the node impedance. However, for applications where source impedance is very high, it may be necessary to limit noise and hum pickup through proper shielding.
- 4. The output stage consists of class AB complementary output drivers, capable of driving a low resistance load. The output voltage swing is limited by the drain to source on-resistance of the output transistors as determined by the bias circuitry, and the value of the load resistor. When connected in the voltage follower configuration, the oscillation resistant feature, combined with the rail to rail input and output feature, makes an effective analog signal buffer for medium to high source impedance sensors, transducers, and other circuit networks.
- 5. The ALD1701A/ALD1701B/ALD1701ALD1701G operational amplifier has been designed to provide full static discharge protection. Internally, the design has been carefully implemented to minimize latch up. However, care must be exercised when handling the device to avoid strong static fields that may degrade a diode junction, causing increased input leakage currents. In using the operational amplifier, the user is advised to power up the circuit before, or simultaneously with any input voltages applied, and to limit input voltages not to exceed 0.3V of the power supply voltage levels.
- 6. The ALD1701A/ALD1701B/ALD1701/ALD1701G, with its micropower operation, offers numerous benefits in reduced power supply requirements, less noise coupling and current spikes, less thermally induced drift, better overall reliability due to lower self heating, and lower input bias current. It requires practically no warm up time as the chip junction heats up to only 0.1°C above ambient temperature under most operating conditions.

### TYPICAL PERFORMANCE CHARACTERISTICS

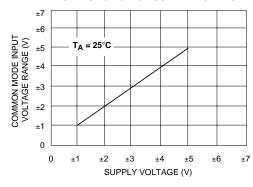
# SUPPLY CURRENT AS A FUNCTION OF SUPPLY VOLTAGE



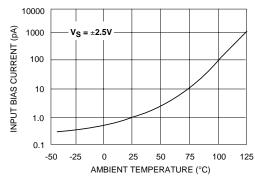
## OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF LOAD RESISTANCE



#### COMMON MODE INPUT VOLTAGE RANGE AS A FUNCTION OF SUPPLY VOLTAGE

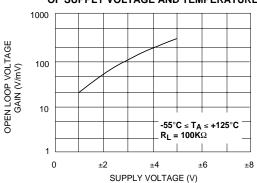


## INPUT BIAS CURRENT AS A FUNCTION OF AMBIENT TEMPERATURE

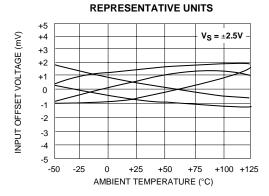


### TYPICAL PERFORMANCE CHARACTERISTICS (cont'd)

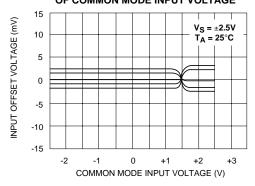
# OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF SUPPLY VOLTAGE AND TEMPERATURE



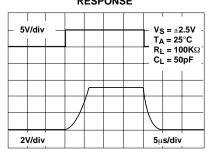
# INPUT OFFSET VOLTAGE AS A FUNCTION OF AMBIENT TEMPERATURE



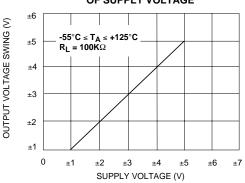
# INPUT OFFSET VOLTAGE AS A FUNCTION OF COMMON MODE INPUT VOLTAGE



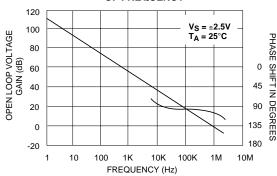
# LARGE - SIGNAL TRANSIENT RESPONSE



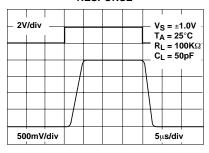
# OUTPUT VOLTAGE SWING AS A FUNCTION OF SUPPLY VOLTAGE



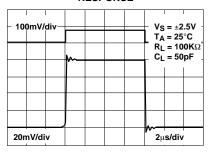
## OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF FREQUENCY



## LARGE - SIGNAL TRANSIENT RESPONSE

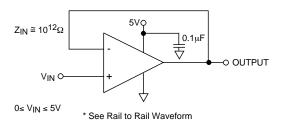


## SMALL - SIGNAL TRANSIENT RESPONSE

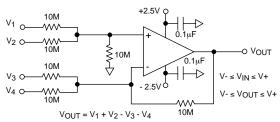


### **TYPICAL APPLICATIONS**

#### **RAIL-TO-RAIL VOLTAGE FOLLOWER/BUFFER**

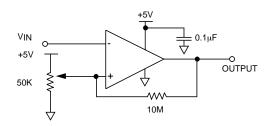


# HIGH INPUT IMPEDANCE RAIL-TO-RAIL PRECISION DC SUMMING AMPLIFIER

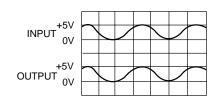


 $R_{IN}$  = 10M $\Omega$  Accuracy limited by resistor tolerances and input offset voltage

### RAIL-TO-RAIL VOLTAGE COMPARATOR

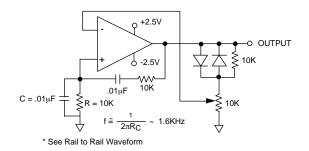


#### **RAIL-TO-RAIL WAVEFORM**

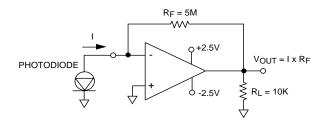


Performance waveforms. Upper trace is the output of a Wien Bridge Oscillator. Lower trace is the output of Rail-to-rail voltage follower.

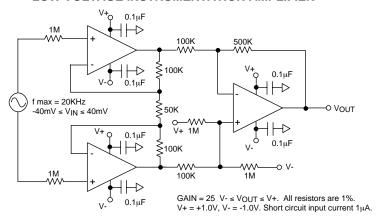
### WIEN BRIDGE OSCILLATOR (RAIL-TO-RAIL) SINE WAVE GENERATOR



# PHOTO DETECTOR CURRENT TO VOLTAGE CONVERTER

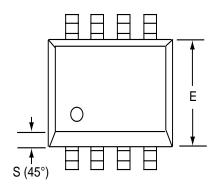


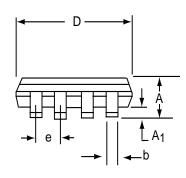
### LOW VOLTAGE INSTRUMENTATION AMPLIFIER



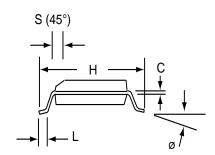
### **SOIC-8 PACKAGE DRAWING**

### 8 Pin Plastic SOIC Package



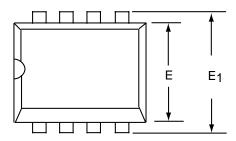


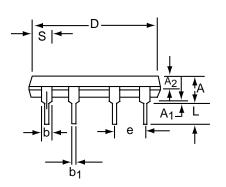
	Millim	neters	Inc	hes		
Dim	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A <sub>1</sub>	0.10	0.25	0.004	0.010		
b	0.35	0.45	0.014	0.018		
С	0.18	0.25	0.007	0.010		
D-8	4.69	5.00	0.185	0.196		
E	3.50	4.05	0.140	0.160		
е	1.27	BSC	0.050	BSC		
н	5.70	6.30	0.224	0.248		
L	0.60	0.937	0.024	0.037		
Ø	0°	8°	0°	8°		
S	0.25	0.50	0.010	0.020		



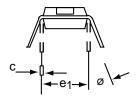
### **PDIP-8 PACKAGE DRAWING**

### 8 Pin Plastic DIP Package



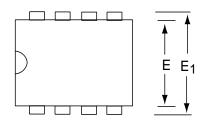


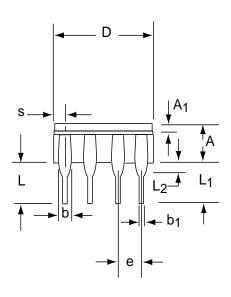
	Millim	neters	Inc	hes
Dim	Min	Max	Min	Max
Α	3.81	5.08	0.105	0.200
A <sub>1</sub>	0.38	1.27	0.015	0.050
A <sub>2</sub>	1.27	2.03	0.050	0.080
b	0.89	1.65	0.035	0.065
b <sub>1</sub>	0.38	0.51	0.015	0.020
С	0.20	0.30	0.008	0.012
D-8	9.40	11.68	0.370	0.460
E	5.59	7.11	0.220	0.280
E <sub>1</sub>	7.62	8.26	0.300	0.325
е	2.29	2.79	0.090	0.110
e <sub>1</sub>	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
S-8	1.02	2.03	0.040	0.080
Ø	0°	15°	0°	15°

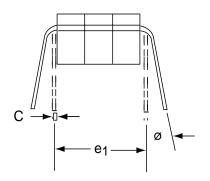


### **CERDIP-8 PACKAGE DRAWING**

### 8 Pin CERDIP Package







	Millin	neters	Inc	hes		
Dim	Min	Max	Min	Max		
Α	3.55	5.08	0.140	0.200		
A <sub>1</sub>	1.27	2.16	0.050	0.085		
b	0.97	1.65	0.038	0.065		
b <sub>1</sub>	0.36	0.58	0.014	0.023		
С	0.20	0.38	0.008	0.015		
D-8		10.29		0.405		
E	5.59	7.87	0.220	0.310		
E <sub>1</sub>	7.73	8.26	0.290	0.325		
е	2.54 E	BSC	0.100	BSC		
e <sub>1</sub>	7.62 E	BSC	0.300	BSC		
L	3.81	5.08	0.150	0.200		
L <sub>1</sub>	3.18		0.125			
L <sub>2</sub>	0.38	1.78	0.015	0.070		
S		2.49		0.098		
Ø	0°	15°	0°	15°		

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